

## Fabrication of LaFeO<sub>3</sub> and rGO-LaFeO<sub>3</sub> Microspheres based Gas Sensors for Detection of NO<sub>2</sub> and CO

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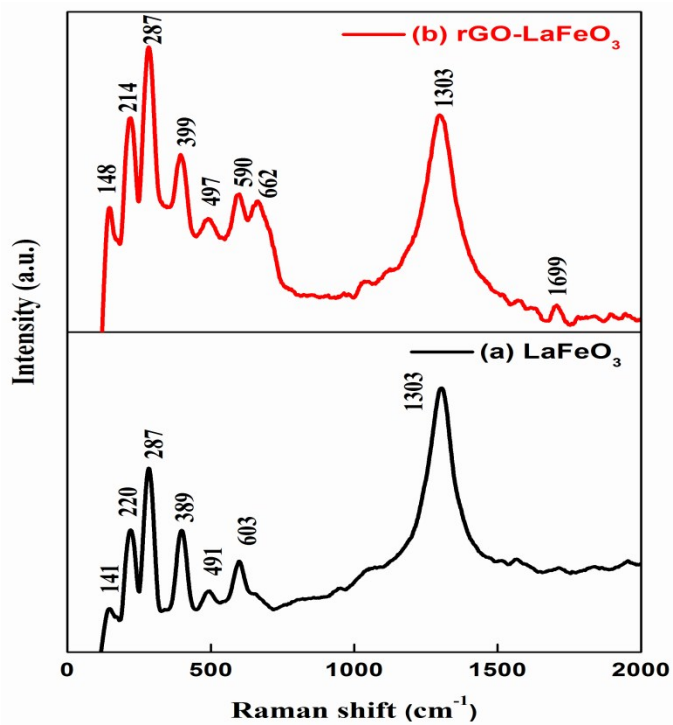
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In current report LaFeO<sub>3</sub> and rGO-LaFeO<sub>3</sub> were synthesized by hydrothermal method and device were fabricated by photolithography technique for detection of different concentration of CO and NO<sub>2</sub> gases at 200 and 250 °C temperatures. Both synthesized microsphere shaped samples were characterized by XRD, Raman, FTIR, TGA, AFM, FESEM, XPS, TEM, UV-Vis, BET, among them some supporting information are presented here.

### Raman Studies:

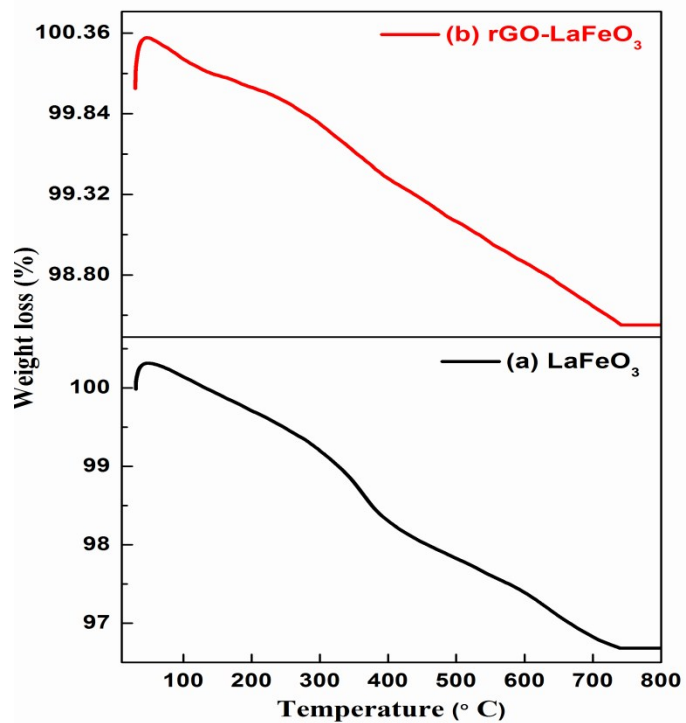
Figure S1 (a) and (b) shows the Raman spectra for LaFeO<sub>3</sub> and rGO-LaFeO<sub>3</sub> at room temperature, to get the information about order-disorder effect in lattice. The bands at around 141, 220, 287, 389, 491, 603, 1303 cm<sup>-1</sup> are corresponding to LaFeO<sub>3</sub>. The bands were observed at 141, 220, 287, 389, 491, 603 and 1303 cm<sup>-1</sup> for LaFeO<sub>3</sub> shown in fig. S1 (a). The two major modes at 287 and 603 cm<sup>-1</sup> attributed to Ag assign mode, two-photon and impurity scattering<sup>1</sup>. The band at 389 cm<sup>-1</sup> assigned to B<sub>3g</sub> mode while 491cm<sup>-1</sup> assign to one-phonon scattering<sup>2</sup>. The band centered at 1303 corresponding to two-phonon scattering. The bands at 141and 220 may be due to some Fe<sub>2</sub>O<sub>3</sub> impurity. Similar behavior was observed for rGO-LaFeO<sub>3</sub> shown in Fig. S1 (b), but higher shifting in wavenumber like 662 cm<sup>-1</sup> is may be due to the reduction of GO. An additional peak appeared at 1699 cm<sup>-1</sup> which is induced defect mode (D') scatter from K to K ( K-point of Brillouin zone) <sup>3,4</sup>, it may be splitting of G band by interaction of vibration mode of impurity with phonon mode of rGO.



**Fig. S1** Raman spectra for  $\text{LaFeO}_3$  (a) and  $\text{rGO-LaFeO}_3$  (b)

### Thermal Studies:

TGA curve of  $\text{LaFeO}_3$  and  $\text{rGO-LaFeO}_3$  shown in Fig. S2 observed three weight loss segments. It can be seen that first weight loss about  $100^\circ\text{C}$  was due to elimination of water molecule and crystallization of material. The second loss was observed between  $220\text{-}389^\circ\text{C}$  due to decomposition of organic compound C-H and C=O. The third weight loss was above  $520^\circ\text{C}$  may be due to decomposition of nitrate ions. After  $730^\circ\text{C}$  no weight loss was observed which confirm possibility of formation of metal oxide phase of  $\text{LaFeO}_3$



**Fig. S2** TGA for LaFeO<sub>3</sub> (a) and rGO-LaFeO<sub>3</sub> (b)

**Elemental Study:**

Figure S3 (a) and (b) shows the EDAX spectra for LaFeO<sub>3</sub> and its composite with rGO (rGO-LaFeO<sub>3</sub>) confirm the presence of element in respective samples. EDAX spectra of LaFeO<sub>3</sub> confirm the presence of La, Fe, and Oxygen in the multilayer structure in table S1 while EDAX spectra for rGO-LaFeO<sub>3</sub> shown in fig. S3 (b) confirmed that La, Fe, O, and carbon were present in that composite describe in table S2. EDAX spectra for rGO-LaFeO<sub>3</sub> shows higher signal of C which indicate large content of rGO.

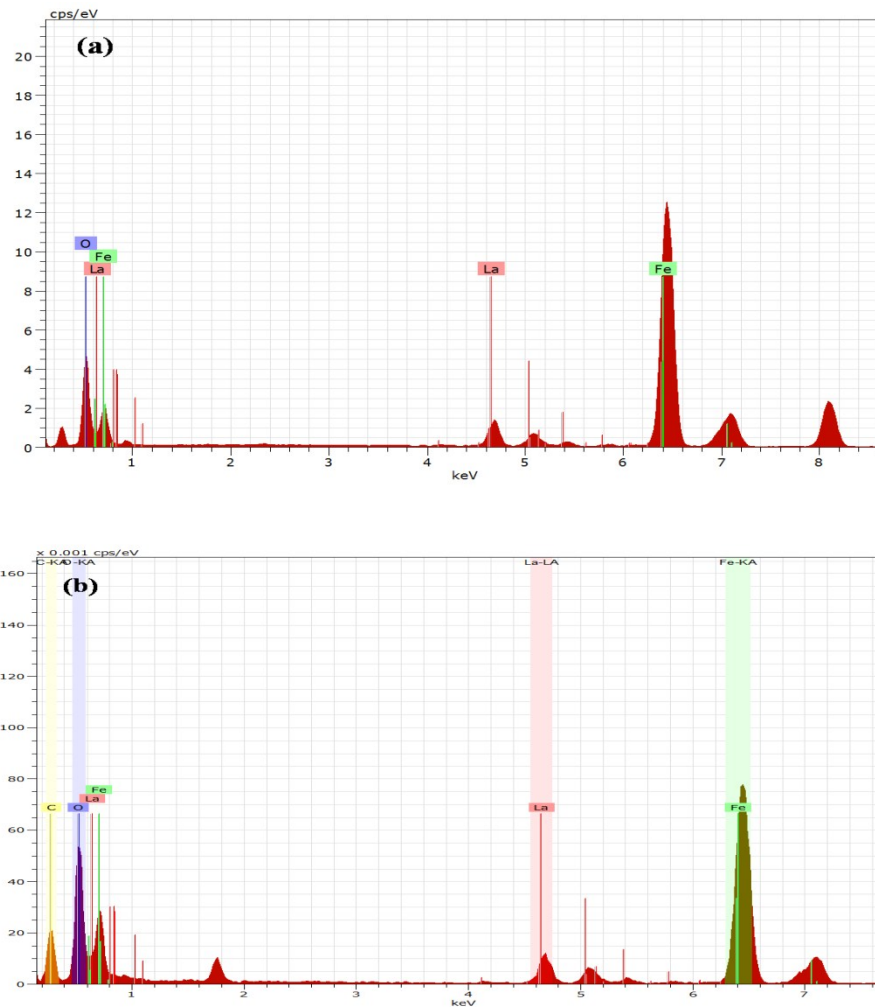


Fig. S3 EDAX spectra of  $\text{LaFeO}_3$  (a) and  $\text{rGO-LaFeO}_3$  (b)

Table S1. Elemental composition of $\text{LaFeO}_3$ by EDAX spectra					
Elements	Series	Unn. [wt. %]	C norm. [wt.%]	C Atom [at. %]	C Error [wt. %]
Fe	K-series	65.72	65.72	49.87	2.01
La	L-series	17.34	17.34	5.29	1.77
O	K-series	16.93	16.93	44.84	0.55

<b>Table S2. Elemental composition of rGO-LaFeO<sub>3</sub> by EDAX spectra</b>					
Elements	Series	Unn. [wt. %]	C norm. [wt.%]	C Atom [at. %]	C Error [wt. %]
Fe	K-series	34.14	34.14	12.67	1.09
La	L-series	12.31	12.31	1.84	1.29
O	K-series	16.03	16.03	20.76	0.55
C	K-series	37.52	37.52	64.74	1.45

### **Atomic Force Microscopy Studies:**

The surface analysis of LaFeO<sub>3</sub> and rGO-LaFeO<sub>3</sub> using AFM with scan area 1 × 1 μm<sup>2</sup> shown in fig. S4 (a) and (b) respectively. The root mean square (RMS) roughness of LaFeO<sub>3</sub> and rGO-LaFeO<sub>3</sub> were 0.707 nm and 6.73 nm respectively. This increment in roughness indicates growth of LaFeO<sub>3</sub> on GO sheets. Higher surface roughness of rGO-LaFeO<sub>3</sub> can enhance the sensing properties as it is directly proportional gas sensitivity. Larger roughness results in larger contact area with the gaseous species, this demonstrates the importance of surface to volume ratio in gas sensing application<sup>5,6</sup>.

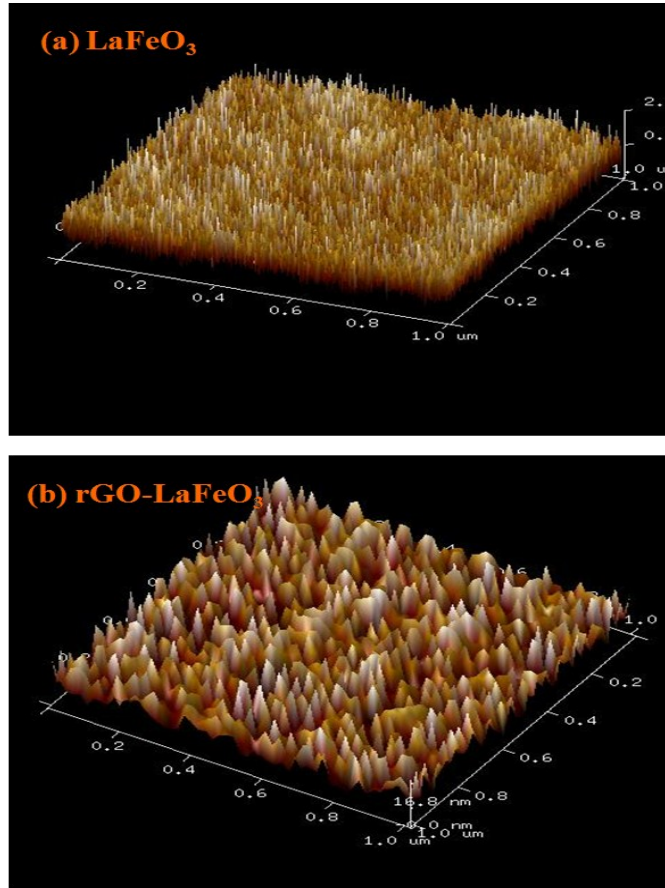


Fig. S4 AFM images-3D view of LaFeO<sub>3</sub> (a) and rGO-LaFeO<sub>3</sub> (b)

### Gas Sensing Mechanism;

#### Carbon Mono Oxide (CO)

Gas sensing mechanism of LaFeO<sub>3</sub> for CO detection can be introduced by the following equation <sup>7</sup>, this will be same for rGO-LaFeO<sub>3</sub>;

- (1) Oxygen molecules in atmosphere adsorb on the LaFeO<sub>3</sub> surface and form O<sup>-</sup>(ads) by attracting electron from the conduction band of LaFeO<sub>3</sub> and gives following reaction.



This increase number of holes in the valance band, which decrease the resistance of p- type LaFeO<sub>3</sub>.

(2) When CO (reducing gas) exposed to LaFeO<sub>3</sub>, a reaction take place between CO and O<sup>-</sup> such way;



Electrons are injected into the valance band and combine with hole which leads to decrease holes concentration and produce increase in the resistance.

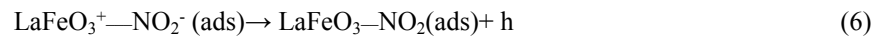
### Nitrogen dioxide (NO<sub>2</sub>)

The gas sensing mechanism of LaFeO<sub>3</sub> with CO and NO<sub>2</sub> takes place as per following ways;

(1) NO<sub>2</sub> molecules capture electrons from LaFeO<sub>3</sub> surface, and form NO<sub>2</sub><sup>-</sup> (ads). Which shows accepting behavior of NO<sub>2</sub><sup>6</sup>.



(2) NO<sub>2</sub> molecule having unpaired electron react with dangling bond on LaFeO<sub>3</sub> surface and capture a lone-pair electron from that which results formation of hole. This increment of hole concentration leads to decrease LaFeO<sub>3</sub> resistance and resistance recover to its initial value <sup>6</sup>.



### Gas sensing comparison table:

<b>Table S3. CO and NO<sub>2</sub> sensitivity of LaFeO<sub>3</sub> and rGO-LaFeO<sub>3</sub> comparison with already published research papers</b>					
Sample	Test gas	Concentration (ppm)	Temperature (°C)	S (%)	Reference(Year)
LaFeO <sub>3</sub>	CO	500	270	0.65	2003 <sup>8</sup>
LaFeO <sub>3</sub>	CO	500	RT	5	2011 <sup>9</sup>
<b>LaFeO<sub>3</sub></b>	<b>CO</b>	<b>5</b>	<b>250</b>	<b>30.9</b>	<b>Current study</b>
<b>rGO-LaFeO<sub>3</sub></b>	<b>CO</b>	<b>5</b>	<b>250</b>	<b>31.9</b>	<b>Current study</b>
LaFeO <sub>3</sub> nanocube	NO <sub>2</sub>	1	25	10.40	2014 <sup>6</sup>
LaFeO <sub>3</sub>	NO <sub>2</sub>	5	150	80.4	2018 <sup>10</sup>

<b>LaFeO<sub>3</sub></b>	<b>NO<sub>2</sub></b>	<b>3</b>	<b>250</b>	<b>144.1</b>	<b>Current study</b>
<b>rGO-LaFeO<sub>3</sub></b>	<b>NO<sub>2</sub></b>	<b>3</b>	<b>250</b>	<b>183.4</b>	<b>Current study</b>

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